

Extended Data Figure 3 | Optical properties of single-junction  $MoSe_2$ –WSe $_2$  lateral heterostructure. a, b, Raman spectra of MoSe $_2$  and WSe $_2$  domains from a single-junction MoSe $_2$ –WSe $_2$  monolayer lateral heterostructure using 514 nm (a) and 613 nm (b) laser excitation. c, Raman spectra at the interfaces of the single-junction MoSe $_2$ –WSe $_2$  lateral heterostructure. d, e, Composite Raman intensity maps at a frequency of 240 cm $^{-1}$  (MoSe $_2$  domain, d), 250 cm $^{-1}$  (WSe $_2$  domain, e). f, Position map corresponding to the optical image in Extended Data

Fig. 2a. **g**, Photoluminescence spectra of MoSe<sub>2</sub>, WSe<sub>2</sub> domains and at the interface of the MoSe<sub>2</sub>–WSe<sub>2</sub> single-junction monolayer lateral heterostructure shown in Extended Data Fig. 2a. **h**–**j**, Photoluminescence intensity maps at 1.53 eV (MoSe<sub>2</sub> domain, **h**) and 1.6 eV (WSe<sub>2</sub> domain, **i**); the composite is shown in **j**. **k**, **l**, Peak width (in eV) map (**k**) and position (in eV) map (**l**) corresponding to the optical image in Extended Data Fig. 2a. Scale bars: **d**–**l**, 10  $\mu$ m.